NSN 5961-01-295-5035

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-295-5035 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage and 20.0 drain to gate voltage and -20.0 gate to source voltage **Current Rating Per Characteristic:** 50.00 milliamperes forward gate current **Power Rating Per Characteristic:** 400.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 95105-204-0016-010 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No